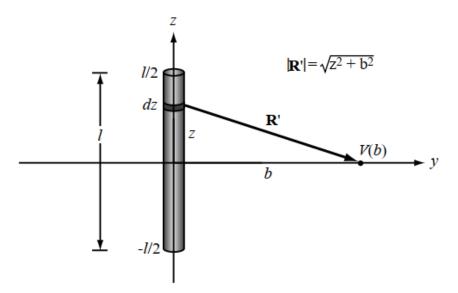
# 2A04 Tutorial 7

March 7<sup>th</sup>, 2022

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Find the electric potential V at a location a distance b from the origin in the x-y plane due to a line charge with charge density  $\rho_l$  and of length l. The line charge is coincident with the z axis and extends from z=-l/2 to z=l/2.



For a line charge, we have the formula:

$$V = \frac{1}{4\pi\varepsilon} \int_{l} \frac{\rho_l}{R'} dl'$$

In this specific case, we can integrate along z with the following limits:

$$V = \frac{\rho_l}{4\pi\varepsilon} \int_{-l/2}^{l/2} \frac{dz}{R'}$$

$$V = \frac{\rho_l}{4\pi\varepsilon} \int_{-l/2}^{l/2} \frac{dz}{\sqrt{z^2 + b^2}}$$

$$V = \frac{\rho_l}{4\pi\varepsilon} \ln\left(\frac{\sqrt{l^2 + 4b^2} + l}{\sqrt{l^2 + 4b^2} - l}\right)$$

$$\int \frac{1}{\sqrt{u^{2}+a^{2}}} dU = |P_{n}(u + \sqrt{u^{2}+a^{2}})| + C$$

$$V = C_{1} \ln \left( z + \sqrt{z^{2} + b^{2}} \right) \Big|_{-2/2}^{2/2} = C_{1} \left( \ln \left( \frac{9}{2} + \sqrt{\frac{9}{2} + b^{2}} \right) - \ln \left( -\frac{1}{2} + \sqrt{\frac{9}{2} + b^{2}} \right) \right)$$

$$V = C_1 cm \left( \frac{Q + \sqrt{4(\sqrt{2} + b^2)}}{-Q + \sqrt{4(\sqrt{2} + b^2)}} \right)$$

A cylindrical bar of silicon has a radius of 4mm and a length of 8cm. If a voltage of 5V is applied between the ends of the bar and  $\mu_e=0.13~\left(\frac{m^2}{v_S}\right)$ ,  $\mu_h=0.13$  $0.05 \left(\frac{m^2}{V_S}\right)$ ,  $N_e = 1.5 \times 10^{16} electrons/m^3$ , and  $N_h = N_e$ , find the following:

- The conductivity of silicon,
- The current *I* flowing in the bar,
- The drift velocities  $\overrightarrow{u_e}$  and  $\overrightarrow{u_h}$ ,
- The resistance of the bar, and
- The power dissipated in the bar.

#### Givens

$$r = 4mm$$

$$l = 8cm$$

$$V = 5V$$

$$\mu_e = 0.13 \left(\frac{m^2}{Vs}\right)$$
 What does each parameter mean???

 $\mu_h = 0.05 \left(\frac{m^2}{Vs}\right)$ 

$$N_e = N_h = 1.5 \times 10^{16} electrons/m^3$$

### 2. Problem 4.41a

A cylindrical bar of silicon has a radius of 4mm and a length of 8cm. If a voltage of 5V is applied between the ends of the bar and  $\mu_e = 0.13 \left(\frac{m^2}{Vs}\right)$ ,  $\mu_h = 0.05 \left(\frac{m^2}{Vs}\right)$ ,  $N_e = 1.5 \times 10^{16} electrons/m^3$ , and  $N_h = N_e$ , find the following:

The conductivity of silicon

How can we calculate conductivity?

#### Givens

$$r = 4mm$$

$$l = 8cm$$

$$V = 5V$$

$$\mu_e = 0.13 \left(\frac{m^2}{Vs}\right)$$

$$\mu_h = 0.05 \left(\frac{m^2}{Vs}\right)$$

$$N_e = N_h = 1.5 \times 10^{16} electrons/m^3$$

$$\sigma = (N_e \mu_e + N_h \mu_h) e \ (\frac{S}{m})$$

$$\sigma = (1.5 \times 10^{16} (0.13 + 0.05))(1.602 \times 10^{-19})$$

$$\sigma = 4.33 \times 10^{-4} \left(\frac{S}{m}\right)$$

# 2. Problem 4.41a

A cylindrical bar of silicon has a radius of 4mm and a length of 8cm. If a voltage of 5V is applied between the ends of the bar and  $\mu_e=0.13~\left(\frac{m^2}{v_S}\right)$  ,  $\mu_h=0.13$  $0.05 \left(\frac{m^2}{V_S}\right)$ ,  $N_e = 1.5 \times 10^{16} electrons/m^3$ , and  $N_h = N_e$ , find the following:

The conductivity of silicon

$$\sigma = 4.33 \times 10^{-4} \left(\frac{S}{m}\right)$$

#### Givens

$$r = 4mm$$

$$l = 8cm$$

$$V = 5V$$

$$\mu_e = 0.13 \left(\frac{m^2}{Vs}\right)$$

$$\mu_h = 0.05 \left(\frac{m^2}{Vs}\right)$$

$$\mu_h = 0.05 \left( \frac{m^2}{Vs} \right)$$

$$N_e = N_h = 1.5 \times 10^{16} electrons/m^3$$

Material	Conductivity σ (S/m)	Material	Conductivity σ (S/m)
Conductors		Semiconductors	
Silver	$6.2 \times 10^{7}$	Dura garmanium	2.2
Copper	$5.8 \times 10^{7}$	Pure silicon	$4.4 \times 10^{-4}$
Gold	$4.1 \times 10^{7}$	I	
Aluminum	$3.5 \times 10^{7}$	Wet soil	$\sim 10^{-2}$
Tungsten	$1.8 \times 10^{7}$	Fresh water	$\sim 10^{-3}$
Zinc	$1.7 \times 10^{7}$	Distilled water	$\sim 10^{-4}$
Brass	$1.5 \times 10^{7}$	Dry soil	$\sim 10^{-4}$
Iron	107	Glass	$10^{-12}$
Bronze	107	Hard rubber	$10^{-15}$
Tin	$9 \times 10^{6}$	Paraffin	$10^{-15}$
Lead	$5 \times 10^{6}$	Mica	$10^{-15}$
Mercury	106	Fused quartz	$10^{-17}$
Carbon	$3 \times 10^{4}$	Wax	$10^{-17}$
Seawater	4	379100	
Animal body (average)	0.3 (poor cond.)		

### 2. Problem 4.41b

A cylindrical bar of silicon has a radius of 4mm and a length of 8cm. If a voltage of 5V is applied between the ends of the bar and  $\mu_e=0.13~\left(\frac{m^2}{v_S}\right)$  ,  $\mu_h=0.13$  $0.05 \left(\frac{m^2}{v_s}\right)$ ,  $N_e = 1.5 \times 10^{16} electrons/m^3$ , and  $N_h = N_e$ , find the following:

The current *I* flowing in the bar

#### Givens

$$r = 4mm$$

$$l = 8cm$$

$$V = 5V$$

$$\mu_e = 0.13 \left(\frac{m^2}{Vs}\right)$$

$$\mu_h = 0.05 \left(\frac{m^2}{Vs}\right)$$

$$\mu_h = 0.05 \left( \frac{m^2}{Vs} \right)$$

$$N_e = N_h = 1.5 \times 10^{16} electrons/m^3$$

How can we compute the current?

$$I = JA$$

$$I = \sigma EA$$

$$I = \sigma \frac{V}{l} \pi r^{2}$$

$$5$$

$$I = (4.33 \times 10^{-4}) \frac{5}{0.08} \pi 0.004^{2}$$

$$I = 1.36 \mu A$$

$$I=1.36\mu A$$

# 2. Problem 4.41c

A cylindrical bar of silicon has a radius of 4mm and a length of 8cm. If a voltage of 5V is applied between the ends of the bar and  $\mu_e = 0.13 \left(\frac{m^2}{Vs}\right)$ ,  $\mu_h = 0.05 \left(\frac{m^2}{Vs}\right)$ ,  $N_e = 1.5 \times 10^{16} electrons/m^3$ , and  $N_h = N_e$ , find the following:

The drift velocities  $\overrightarrow{u_e}$  and  $\overrightarrow{u_h}$ 

#### Givens

$$r = 4mm$$

$$l = 8cm$$

$$V = 5V$$

$$\mu_e = 0.13 \left(\frac{m^2}{Vs}\right)$$

$$\mu_h = 0.05 \left( \frac{m^2}{Vs} \right)$$

$$N_e = N_h = 1.5 \times 10^{16} electrons/m^3$$

From the definition of the mobility:

$$\overrightarrow{u_e} = -\mu_e \overrightarrow{E}, \quad \overrightarrow{u_h} = \mu_h \overrightarrow{E}$$

$$\overrightarrow{u_e} = -\mu_e E \frac{\overrightarrow{E}}{E}, \qquad \overrightarrow{u_h} = \mu_h E \frac{\overrightarrow{E}}{E}$$

What is the fraction at the end there? Why do we need it?

$$\overrightarrow{u_e} = -\mu_e \frac{V}{l} \widehat{\boldsymbol{E}}, \qquad \overrightarrow{u_h} = \mu_h \frac{V}{l} \widehat{\boldsymbol{E}}$$

$$\overrightarrow{u_e} = -0.13 \frac{5}{0.08} \widehat{\boldsymbol{E}}, \quad \overrightarrow{u_h} = 0.05 \frac{5}{0.08} \widehat{\boldsymbol{E}}$$

$$\overrightarrow{u_e} = -8.125\widehat{E}, \quad \overrightarrow{u_h} = 3.125\widehat{E}$$

# 2. Problem 4.41d,e

A cylindrical bar of silicon has a radius of 4mm and a length of 8cm. If a voltage of 5V is applied between the ends of the bar and  $\mu_e=0.13~\left(\frac{m^2}{v_S}\right)$  ,  $\mu_h=0.13$  $0.05 \left(\frac{m^2}{v_s}\right)$ ,  $N_e = 1.5 \times 10^{16} electrons/m^3$ , and  $N_h = N_e$ , find the following:

Resistance of, and power dissipated across, the bar.

#### Givens

$$r = 4mm$$

$$l = 8cm$$

$$V = 5V$$

$$\mu_e = 0.13 \left(\frac{m^2}{Vs}\right)$$

$$\mu_h = 0.05 \left(\frac{m^2}{Vs}\right)$$

$$\mu_h = 0.05 \left(\frac{m^2}{Vs}\right)$$

$$N_e = N_h = 1.5 \times 10^{16} electrons/m^3$$

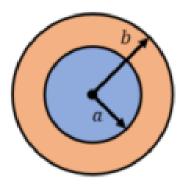
We already found  $I = 1.36\mu A$ . How can we find the resistance?

Ohm's Law: 
$$R = \frac{V}{I} = \frac{5}{1.36 \times 10^{-6}} = 3.68 \, M\Omega$$

With the same parameters, we can find the power dissipated:

$$P = VI = 5(1.36 \times 10^{-6}) = 6.8 \,\mu W$$

A coaxial resistor of length l consists of two concentric cylinders. The inner cylinder has radius a and is made of a material with conductivity  $\sigma_1$ , and the outer cylinder, extending between r = a and r = b, is made of a material with conductivity  $\sigma_2$ . If the two ends of the resistor are capped with conducting plates, show that the resistance between the two ends is



These are basically parallel resistors!

$$R = \left(\frac{1}{R_1} + \frac{1}{R_2}\right)^{-1}$$

$$R = \frac{l}{\pi(\sigma_1 a^2 + \sigma_2(b^2 - a^2))}.$$

So how can we find  $R_1$  and  $R_2$ ?

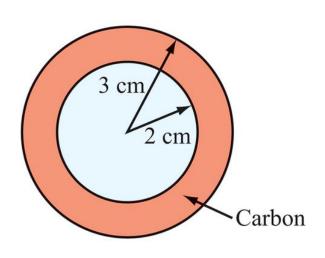
Each *R* will follow  $R = \frac{l}{\sigma A}$  where *A* is the surface area.

$$R = \left(\frac{1}{R_1} + \frac{1}{R_2}\right)^{-1} = \left(\frac{\sigma_1 A_1}{l} + \frac{\sigma_2 A_2}{l}\right)^{-1} \dots \text{ what are the areas?}$$

$$R = \left(\frac{\sigma_1 \pi a^2}{l} + \frac{\sigma_2 \pi (b^2 - a^2)}{l}\right)^{-1} = \left(\frac{\sigma_1 \pi a^2 + \sigma_2 \pi (b^2 - a^2)}{l}\right)^{-1}$$

$$R = \frac{l}{\sigma_1 \pi a^2 + \sigma_2 \pi (b^2 - a^2)} = \frac{l}{\pi (\sigma_1 a^2 + \sigma_2 (b^2 - a^2))}$$

Apply the result of Problem 4.44 (that's the one we just did!) to find the resistance of a 20 cm long hollow cylinder made of carbon with  $\sigma = 3 \times 10^4$  S/m.



$$R = \frac{l}{\pi(\sigma_1 a^2 + \sigma_2(b^2 - a^2))}.$$

$$Givens$$

$$a = 2cm$$

$$b = 3cm$$

$$\sigma = 3 \times 10^4 \text{ S/m}$$

$$l = 20cm$$

Which  $\sigma$  is the given value? And what's the other value?

Cylinder is hollow... so take  $\sigma_1 = 0$  and  $\sigma_2 = 3 \times 10^4 \, S/m$ 

$$R = \frac{0.2}{\pi ((0)(0.02)^2 + (3 \times 10^4)(0.03^2 - 0.02^2))}$$
$$= \frac{0.2}{\pi ((3 \times 10^4)(5 \times 10^{-4}))} = 4.2 \, m\Omega$$

# Reminders

- Assignment 7 is out, and is due at 8AM on March 14.
- Complete the mid-semester survey for a 5% bonus on Assignment 7! Survey must be completed by Sunday March 13<sup>th</sup>.
- Have a great week!